

S-82B4A/5A Series

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BATTERY PROTECTION IC FOR 4-SERIAL OR 5-SERIAL CELL PACK

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This IC is a protection IC for lithium-ion rechargeable batteries, which includes high-accuracy voltage detection circuits and delay circuits. It is suitable for protecting 4-serial or 5-serial cell lithium-ion rechargeable battery packs from overcharge, overdischarge, and overcurrent.

■ Features

High-accuracy voltage detection for each cell

Overcharge detection voltage n 3.900 V to 4.500 V (25 mV step) Accuracy $\pm 20 \text{ mV}$ Overcharge release voltage n 3.500 V to 4.500 V^{*1} Accuracy $\pm 50 \text{ mV}$ Overdischarge detection voltage n 2.000 V to 3.200 V (100 mV step) Accuracy $\pm 50 \text{ mV}$ Overdischarge release voltage n 2.000 V to 3.400 V^{*2} Accuracy $\pm 100 \text{ mV}$

• Three-level discharge overcurrent detection

Discharge overcurrent 1 detection voltage

10 mV to 200 mV (5 mV step)

Discharge overcurrent 2 detection voltage

20 mV to 300 mV (5 mV step)

Accuracy ±5 mV

20 mV to 300 mV (5 mV step)

Accuracy ±10 mV

50 mV to 400 mV (10 mV step)

Accuracy ±20 mV

Charge overcurrent detection

Charge overcurrent detection voltage -200 mV to -10 mV (5 mV step) Accuracy $\pm 5 \text{ mV}$

Discharge overcurrent 1 detection delay time is settable by an external capacitor (The other delay time are internally fixed)

• Power saving control by a control pin

0 V battery charge: Enabled, inhibited
 Power-down function: Available, unavailable

Release condition of discharge overcurrent status:
 Load disconnection, charger connection

• Output voltage of CO and DO pin is limited to VC2 pin voltage. (S-82B5A Series)

High-withstand voltage:
 Absolute maximum rating 28.0 V

Wide operating voltage range: 5.0 V to 24.0 V
 Wide operation temperature range: Ta = -40°C to +85°C

• Low current consumption

During operation: 4.0 μ A typ., 8.0 μ A max. (Ta = +25°C) During power-down: 0.1 μ A max. (Ta = +25°C) During power-saving: 0.1 μ A max. (Ta = +25°C)

• Lead-free (Sn 100%), halogen-free

- *1. Overcharge release voltage = Overcharge detection voltage Overcharge hysteresis voltage (Overcharge hysteresis voltage n can be selected from a range of 0 V to 0.4 V in 50 mV steps.)
- *2. Overdischarge release voltage = Overdischarge detection voltage + Overdischarge hysteresis voltage (Overdischarge hysteresis voltage n can be selected from a range of 0 V to 0.7 V in 100 mV steps.)

Remark n = 1, 2, 3, 4, 5

■ Applications

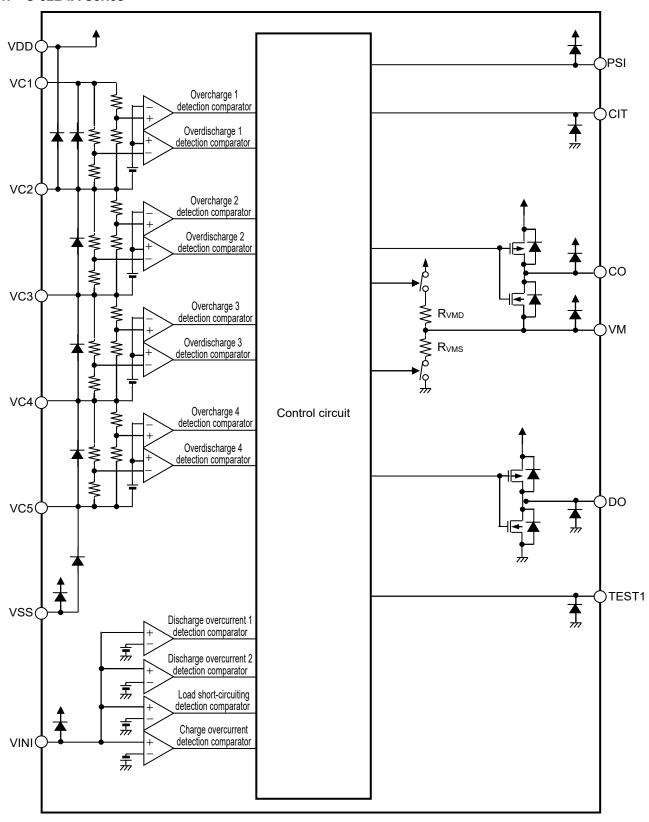
Lithium-ion rechargeable battery packs

■ Package

16-Pin TSSOP

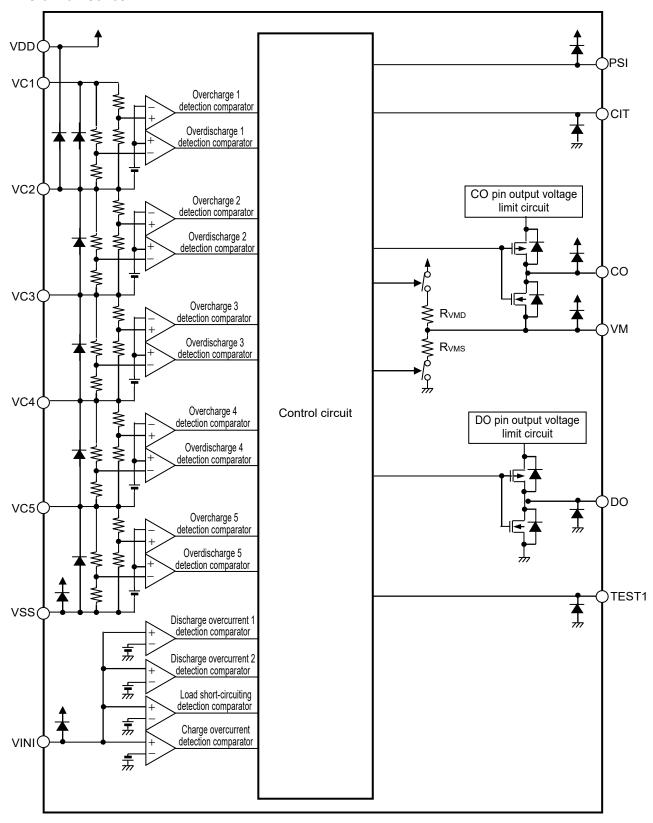
■ Block Diagram

1. S-82B4A Series



Remark Diodes in the figure are parasitic diodes.

2. S-82B5A Series

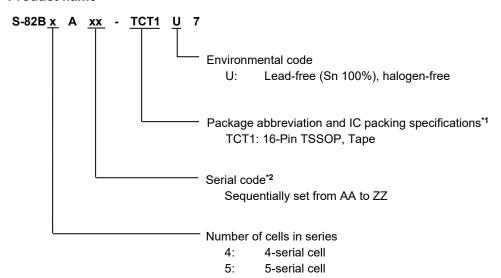


Remark Diodes in the figure are parasitic diodes.

Figure 2

■ Product Name Structure

1. Product name



- *1. Refer to the tape drawing.
- *2. Refer to "3. Product name list".

2. Package

Table 1 Package Drawing Codes

Package Name	Dimension	Tape	Reel	
16-Pin TSSOP	FT016-A-P-SD	FT016-A-C-SD	FT016-A-R-S1	

3. Product name list

3. 1 S-82B5A Series

Table 2 (1 / 2)

Product Name	Overcharge Detection Voltage [Vcu]	Overcharge Release Voltage [V _{CL}]	Overdischarge Detection Voltage [V _{DL}]	Overdischarge Release Voltage [V _{DU}]	Discharge Overcurrent 1 Detection Voltage [V _{DIOV1}]	Discharge Overcurrent 2 Detection Voltage [V _{DIOV2}]	Load Short-circuiting Detection Voltage [Vshort]	Charge Overcurrent Detection Voltage [Vclov]
S-82B5AAA-TCT1U7	4.225 V	4.025 V	2.500 V	2.500 V	50 mV	100 mV	400 mV	−50 mV

Table 2 (2 / 2)

Product Name	Delay Time Combination ^{*1}	0 V Battery Charge	Power-down Function	Release Condition of Discharge Overcurrent Status* ²
S-82B5AAA-TCT1U7	(1)	Inhibited	Available	Load disconnection

- *1. Refer to **Table 3** about the details of the delay time combinations.
- *2. Release condition of discharge overcurrent status: Load disconnection, charger connection

Remark Please contact our sales representatives for products other than the above.

Table 3

Dolov Time	Overcharge Detection	Overdischarge Detection	Discharge Overcurrent 2	Charge Overcurrent
Delay Time Combination	Delay Time	Delay Time	Detection Delay Time	Detection Delay Time
Combination	[tcu]	[t _{DL}]	[t _{DIOV2}]	[tciov]
(1)	1.0 s	128 ms	16 ms	16 ms

Remark The delay times can be changed within the range listed in **Table 4**. For details, please contact our sales representatives.

Table 4

Delay Time	Symbol		Selection Range						Remark		
Overcharge detection delay time	tcu	256 ms	512 ms	1.0 s	2.0 s	_	-	-	Select a value from the left.		
Overdischarge detection delay time	t_{DL}	32 ms	64 ms	128 ms	256 ms	512 ms	1.0 s	-	Select a value from the left.		
Discharge overcurrent 2 detection delay time	t _{DIOV2}	4 ms	8 ms	16 ms	32 ms	64 ms	-	-	Select a value from the left.		
Charge overcurrent detection delay time	tciov	4 ms	8 ms	16 ms	32 ms	64 ms	128 ms	256 ms	Select a value from the left.		

■ Pin Configuration

1. 16-Pin TSSOP

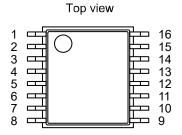


Figure 3

Table 5

Pin No.	Symbol	Description
1	VC1	Connection pin for battery 1's positive voltage
	\/C0	Connection pin for battery 1's negative voltage,
2	VC2	Connection pin for battery 2's positive voltage
3	VC3	Connection pin for battery 2's negative voltage,
3	VC3	Connection pin for battery 3's positive voltage
4	VC4	Connection pin for battery 3's negative voltage,
4	V 04	Connection pin for battery 4's positive voltage
5	VC5	Connection pin for battery 4's negative voltage,
3	VC3	Connection pin for battery 5's positive voltage
6	VSS	Input pin for negative power supply,
	V 3 3	Connection pin for battery 5's negative voltage
7	VINI	Voltage detection pin between VSS pin and VINI pin
8	CIT	Capacitor connection pin for discharge overcurrent
0	CII	1 detection delay time
9	NC*1	No connection
10	TEST1*2	Test pin
11	PSI	Control pin for power-saving
40	D.O.	Connection pin of discharge control FET gate
12	DO	(CMOS output)
13	NC*1	No connection
4.4	00	Connection pin of charge control FET gate
14	CO	(CMOS output)
15	VM	Voltage detection pin between VSS pin and VM pin
10	VDD	Input pin for positive power supply,
16	VDD	Connection pin for battery 1's positive voltage

^{*1.} The NC pin is electrically open. The NC pin can be connected to the VDD pin or the VSS pin.

^{*2.} Set the TEST1 pin open in use.

■ Absolute Maximum Ratings

Table 6

(Ta = +25°C unless otherwise specified)

Item	Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	V _{DS}	VDD	Vss - 0.3 to Vss + 28.0	V
		VC1	$V_{VC2} - 0.3$ to $V_{VC2} + 6.0$	V
Input pin voltage 1	V _{IN1}	VC3	$V_{VC4} - 0.3$ to $V_{DD} + 0.3 \le V_{VC4} + 6.0$	V
		VC4	$V_{VC5} - 0.3$ to $V_{DD} + 0.3 \le V_{VC5} + 6.0$	V
Input pin voltage 2	V _{IN2}	VC2	$V_{DD} - 6.0 \le V_{VC3} - 0.3$ to $V_{DD} + 0.3 \le V_{VC3} + 6.0$	V
Input pin voltage 3	V _{IN3}	VC5	$V_{SS} - 0.3$ to $V_{DD} + 0.3 \le V_{SS} + 6.0$	V
Input pin voltage 4	V _{IN4}	TEST1, CIT	$V_{SS}-0.3$ to $V_{SS}+6.0$	V
Input pin voltage 5	V _{IN5}	PSI, VM, VINI	V_{DD} – 28.0 to V_{DD} + 0.3	V
Output pin voltage 1	V _{OUT1}	DO	$V_{SS}-0.3$ to $V_{DD}+0.3 \leq V_{SS}+28.0$	V
Output pin voltage 2	V _{OUT2}	СО	$V_{DD}-28.0 \leq V_{VM}-0.3$ to $V_{DD}+0.3$	V
Operation ambient temperature	T _{opr}	_	-40 to +85	°C
Storage temperature	T _{stg}	_	-55 to +125	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ Thermal Resistance Value

Table 7

Item	Symbol	Cond	Min.	Тур.	Max.	Unit	
	θја	16-Pin TSSOP	Board A	1	88	1	°C/W
			Board B	_	74	_	°C/W
Junction-to-ambient thermal resistance*1			Board C	ı		ı	°C/W
			Board D	1	1	1	°C/W
			Board E	1	-	1	°C/W

^{*1.} Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ **Power Dissipation**" and "**Test Board**" for details.

■ Electrical Characteristics

Table 8 (1 / 2)

 $(V1 = V2 = V3 = V4 = V5 = 3.5 \text{ V}, \text{ Ta} = +25^{\circ}\text{C} \text{ unless otherwise specified})$

		(71 72 70	V 1 V 0.0 V	, ru 120	C unless otherw	ioo op	oomoa
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Detection Voltage							
Overcharge detection voltage n	V_{CUn}	_	$V_{\text{CU}}-0.020$	Vcu	$V_{CU} + 0.020$	٧	1
Overcharge release voltage n	V _{CLn}	_	V _{CL} - 0.050	VcL	V _{CL} + 0.050	V	1
Overdischarge detection voltage n	V_{DLn}	_	V _{DL} - 0.050	V_{DL}	V _{DL} + 0.050	V	1
Overdischarge release voltage n	V_{DUn}	_	V _{DU} - 0.100	V _{DU}	V _{DU} + 0.100	V	1
Discharge overcurrent 1 detection voltage	V _{DIOV1}	_	V _{DIO1V} – 5	V _{DIOV1}	V _{DIOV1} + 5	mV	1
Discharge overcurrent 2 detection voltage	V_{DIOV2}	_	V _{DIOV2} – 10	V _{DIOV2}	V _{DIOV2} + 10	mV	1
Load short-circuiting detection voltage	Vshort	_	Vshort – 20	Vshort	Vshort + 20	mV	1
Charge overcurrent detection voltage	Vciov	_	Vciov – 5	Vciov	Vciov + 5	mV	1
Delay Time						•	
CIT pin charge current	Ісіт	_	80	120	170	nA	1
CIT pin detection voltage	Vcit	_	1.1	1.2	1.3	٧	1
Overcharge detection delay time	tcu	_	tcu × 0.7	tcu	tcu × 1.3	_	1
Overdischarge detection delay time	t DL	_	$t_{\text{DL}}\times 0.7$	t DL	$t_{\text{DL}} \times 1.3$	_	1
Discharge overcurrent 2 detection delay time	tdiov2	_	$t_{\text{DIOV2}}\times0.7$	tdiov2	$t_{\text{DIOV2}} \times 1.3$	-	1
Load short-circuiting detection delay time	t short	Internally fixed delay time	100	300	600	μs	1
Charge overcurrent detection delay time	tciov	_	t ciov \times 0.7	tciov	tciov × 1.3	_	1
PSI pin response time	t psi	_	1.4	2.0	2.6	ms	1
0 V Battery Charge	•						
0 V battery charge starting charger voltage	V ₀ CHA	0 V battery charge enabled		8.0	1.5	V	1
0 V battery charge inhibition battery voltage n	Voinh	0 V battery charge inhibited	1.0	1.2	1.5	V	1

Remark n = 1, 2, 3, 4, 5

Table 8 (2 / 2)

(V1 = V2 = V3 = V4 = V5 = 3.5 V, $Ta = +25^{\circ}C$ unless otherwise specified)

		(VI - VZ - V3 - V4 - V5 - 3)	.o v, ra -	120 O dillo	o othorw	00 0	comoa
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Internal Resistance							
Resistance between VDD pin and VM pin	R _{VMD}	_	0.5	1	1.5	$M\Omega$	1
Resistance between VM pin and VSS pin	R _{VMS}	_	7.5	15	30	kΩ	1
Input Voltage							
Operation voltage between VDD pin and		Fixed output voltage of DO			24.0		
VSS pin	VDSOP	pin and CO pin	5.0	_	24.0	V	1
External control input pin	•						
PSI pin reverse voltage "H"	V _{PSIH}	_	0.8	1.0	1.3	V	1
PSI pin reverse voltage "L"	V _{PSIL}	_	0.5	0.8	1.0	V	1
Input Current							
Current consumption during operation	IOPE	-	_	4	8	μΑ	1
Current consumption during power-down	I _{PDN}	-	_	_	0.1	μΑ	1
Current consumption during	1				0.1	μА	1
power-saving	Ipsv	_	_	_			I
VC1 pin current	I _{VC1}	_	_	0.25	0.4	μΑ	1
VC2 pin current	Ivc2	-	-0.4	0.05	0.4	μΑ	1
VC3 pin current	Ivcз	-	-0.4	-0.1	0.4	μΑ	1
VC4 pin current	I _{VC4}	-	-0.4	-0.1	0.4	μΑ	1
VC5 pin current	Ivc5	_	-0.4	-0.1	0.4	μΑ	1
PSI pin current "H"	I _{PSIH}	_	-400	-200	-100	nΑ	1
PSI pin current "L"	I _{PSIL}	_	100	200	400	nA	1
Output pin							
CO pin voltage "H"	V _{сон}	4-serial cell	_	-	V_{DD}	V	1
CO pili voltage H	V COH	5-serial cell	-	V _{VC2} - 0.5	V _{VC2}	٧	1
DO pin voltage "H"	V _{DOH}	4-serial cell	_	_	V _{DD}	٧	1
DO pili voltage H	V DOH	5-serial cell	_	V _{VC2} - 0.5	V _{VC2}	V	1
CO pin source current	Ісон	_	10	_	-	μΑ	1
CO pin sink current	Icol	_	180	200	-	μΑ	1
DO pin source current	Ірон	-	10		1	μΑ	1
DO pin sink current	I _{DOL}		1700	2000	-	μΑ	1

■ Test Circuits

Caution Unless otherwise specified, the output voltage levels "H" and "L" at CO pin (V_{CO}) and DO pin (V_{DO}) are judged as follows.

L: $[V_{CO}, V_{DO}] \le V_{DS} \times 0.1 \text{ V}$ H: $[V_{CO}, V_{DO}] > V_{DS} \times 0.1 \text{ V}$

Remark V_{DS}: Input voltage between VDD pin and VSS pin (V1 + V2 + V3 + V4 + V5)

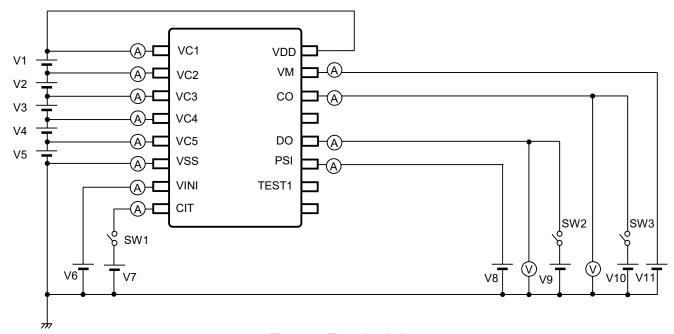


Figure 4 Test circuit 1

This section provides explanations of Test items using Test circuit 1.

Perform each test after setting as shown in Table 9.

	Table 9 Initial Setting of Test Circuit 1 (1 / 2)													
Symbol	V1	V2	V3	V4	V5	V6	V7	V8	V9	V10	V11	SW1	SW2	SW3
Setting	3.5 V	3.5 V	3.5 V	3.5 V	3.5 V	0 V	0 V	V _{DS}	_	-	0 V	ON	OFF	OFF

1. Overcharge detection voltage n (Vcun), overcharge release voltage n (VcLn)

Overcharge detection voltage 1 (V_{CU1}) is defined as the voltage V1 at which V_{CO} goes from "H" to "L" when the voltage V1 is gradually increased after setting V1 = V2 = V3 = V4 = V5 = $V_{\text{CUn}} - 0.05$ V. Overcharge release voltage 1 (V_{CL1}) is defined as the voltage V1 at which V_{CO} goes from "L" to "H" when the voltage V1 is then gradually decreased after setting V2 = V3 = V4 = V5 = $V_{\text{CLn}} - 0.05$ V, V11 = 0.2 V.

Overcharge detection voltage n (V_{CUn}) and overcharge release voltage n (V_{CLn}) (n = 2 to 5) can be determined in the same way as when n = 1.

2. Overdischarge detection voltage n (V_{DLn}), overdischarge release voltage n (V_{Dun})

Overdischarge detection voltage 1 (V_{DL1}) is defined as the voltage V1 at which V_{D0} goes from "H" to "L" when the voltage V1 is gradually decreased. Overdischarge release voltage 1 (V_{DU1}) is defined as the voltage V1 at which V_{D0} goes from "L" to "H" when the voltage V1 is then gradually increased after setting V11 = 0.2 V. Overdischarge detection voltage n (V_{DLn}) and overdischarge release voltage n (V_{DUn}) (n = 2 to 5) can be determined in the same way as when n = 1.

3. Discharge overcurrent 1 detection voltage (VDIOV1)

Discharge overcurrent 1 detection voltage (V_{DIOV1}) is defined as the voltage V6 at which CIT pin current changes from the direction of flowing into the IC to the direction of flowing out from the IC when the voltage V6 is gradually increased after setting V7 = 0.01 V.

4. Discharge overcurrent 2 detection voltage (VDIOV2)

Discharge overcurrent 2 detection voltage (V_{DIOV2}) is defined as the voltage V6 at which V_{DO} goes from "H" to "L" when the voltage V6 is gradually increased after setting V11 = 0.5 V.

5. Load short-circuiting detection voltage (VSHORT)

Load short-circuiting detection voltage (V_{SHORT}) is defined as the voltage V6 at which delay time from when V6 is increased after setting V11 = 0.5 V to when V_{DO} goes from "H" to "L" is load short-circuiting detection delay time (t_{SHORT}).

6. Charge overcurrent detection voltage (Vciov)

Charge overcurrent detection voltage (V_{CIOV}) is defined as the voltage V6 at which V_{CO} goes from "H" to "L" when the voltage V6 is gradually decreased after setting V11 = -0.1 V.

7. CIT pin charge current (ICIT), CIT pin detection voltage (VCIT)

CIT pin charge current (I_{CIT}) is defined as the CIT pin current when setting V6 = ($V_{DIOV1} + V_{DIOV2}$) / 2. CIT pin detection voltage (V_{CIT}) is defined as the voltage V7 at which V_{DO} goes from "H" to "L" when the voltage V7 is then gradually increased.

8. Overcharge detection delay time (tcu)

Overcharge detection delay time (t_{CU}) is the time period from when the voltage V1 exceeds V_{CU1} after setting V1 = V2 = V3 = V4 = V5 = 3.5 V till when V_{CO} goes from "H" to "L".

9. Overdischarge detection delay time (t_{DL})

Overdischarge detection delay time (t_{DL}) is the time period from when the voltage V1 falls below V_{DL1} after setting V1 = V2 = V3 = V4 = V5 = 3.5 V till when V_{DO} goes from "H" to "L".

10. Discharge overcurrent 2 detection delay time (tDIOV2)

Discharge overcurrent 2 detection delay time (t_{DIOV2}) is the time period from when the voltage V6 exceeds V_{DIOV2} after setting V11 = 0.5 V till when V_{DO} changes from "H" to "L".

11. Load short-circuiting detection delay time (tshort)

Load short-circuiting detection delay time (t_{SHORT}) is the time period from when the voltage V6 exceeds V_{SHORT} after setting V11 = 0.5 V till when V_{DO} changes from "H" to "L".

12. Charge overcurrent detection delay time (tciov)

Charge overcurrent detection delay time (t_{CIOV}) is the time period from when the voltage V6 falls below V_{CIOV} after setting V11 = -0.1 V till when V_{CO} changes from "H" to "L".

13. PSI pin response time (t_{PSI})

PSI pin response time (t_{PSI}) is the time period from when the voltage V8 is changed to 0 V till when V_{DO} changes from "H" to "L".

14. 0 V battery charge starting charger voltage (V_{0CHA}) (0 V battery charge enabled)

This IC reaches the overdischarge status after setting V1 = $V_{DL1} - 0.1$ V. Then set V1 = V2 = V3 = V4 = V5 = 0 V. 0 V battery charge starting charger voltage (V_{0CHA}) is defined as the absolute value of voltage V11 at which I_{CO} exceeds 1.0 μ A when the voltage V11 is then gradually decreased after setting SW3 ON and V10 = V11 = -0.5 V.

15. 0 V battery charge inhibition battery voltage n (Voinhn) (0 V battery charge inhibited)

0 V battery charge inhibition battery voltage 1 (V_{0INH1}) is defined as the voltage V1 at which V_{CO} goes from "H" to "L" when the voltage V1 is gradually decreased after setting V1 = V2 = V3 = V4 = V5 = $V_{DLn} - 0.1$ V.

0 V battery charge inhibition battery voltage n (VolNHn) (n = 2 to 5) can be determined in the same way as when n = 1.

16. Resistance between VM pin and VDD pin (R_{VMD})

Resistance between VM pin and VDD pin (R_{VMD}) is defined by $R_{VMD} = (V_{DS} + 0.1) / I_{VM}$ using I_{VM} when setting V1 = V2 = V3 = V4 = V5 = 1.5 V and V11= -0.1 V.

17. Resistance between VM pin and VSS pin (R_{VMS})

Resistance between VM pin and VSS pin (R_{VMS}) is defined by R_{VMS} = V11 / I_{VM} using I_{VM} when setting V6 = 1.0 V and V11 = 2.0 V.

18. PSI pin reverse voltage "H" (VPSIH)

PSI pin reverse voltage "H" (V_{PSIH}) is defined as the voltage V8 at which V_{DO} goes from "L" to "H" when the voltage V8 is gradually increased after setting V8 = 0 V.

19. PSI pin reverse voltage "L" (V_{PSIL})

PSI pin reverse voltage "L" (V_{PSIL}) is defined as the voltage V8 at which V_{DO} goes from "H" to "L" when the voltage V8 is gradually decreased.

20. Current consumption during operation (IOPE)

Current consumption during operation (IOPE) is defined as the sum of VSS pin current, VM pin current and VINI pin current after setting SW1 OFF.

21. Current consumption during power-down (IPDN)

Current consumption during power-down (IPDN) is defined as Ivss under the setting conditions of V1 = V2 = V3 = V4 = V5 = 1.5 V and V11 = V_{DS} .

22. Current consumption during power-saving (IPSV)

Current consumption during power-saving (I_{PSV}) is defined as I_{VSS} under the setting conditions of V8 = 0 V and V11 = V_{DS} .

23. PSI pin current "H" (IPSIH), PSI pin current "L" (IPSIL)

PSI pin current "H" (I_{PSIH}) is defined as I_{PSI} when setting V8 = V_{DS} - 1 V after setting V8 = V_{DS}. PSI pin current "L" (I_{PSIL}) is defined as I_{PSI} when setting V8 = (V_{PSIH} + V_{PSIL}) / 2 after setting V8 = 0 V.

24. CO pin voltage "H" (Vcoh), CO pin source current (Icoh)

CO pin voltage "H" (V_{COH}) is defined as CO pin voltage (V_{CO}) in the settings shown in **Table 9**. CO pin source current (I_{COH}) is defined as I_{CO} when setting V10 = V_{COH} – 0.5 V and SW3 ON.

25. CO pin sink current (Icol)

CO pin sink current (I_{COL}) is defined as I_{CO} when setting V1 = V_{CU1} + 0.1 V, V10 = 0.5 V and SW3 ON.

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26. DO pin voltage "H" (V_{DOH}), DO pin source current (I_{DOH})

DO pin voltage "H" (V_{DOH}) is defined as DO pin voltage (V_{DO}) in the settings shown in **Table 9**. DO pin source current (I_{DOH}) is defined as I_{DO} when setting V9 = V_{DOH} – 0.5 V and SW2 ON.

27. DO pin sink current (IDOL)

DO pin sink current (I_{DOL}) is defined as I_{DO} when setting V1 = $V_{DL1} - 0.1$ V, V9 = 0.5 V and SW2 ON.

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Operation

Remark Refer to "■ Battery Protection IC Connection Example".

1. Normal status

The status when the CO pin output voltage (V_{CO}) = "H" and DO pin output voltage (V_{DO}) = "H" is the normal status. CO pin voltage "H" (V_{COH}) is the voltage V_{CO} when the V_{CO} is "H". DO pin voltage "H" (V_{DOH}) is the voltage V_{DO} when the V_{DO} is "H".

All the conditions mentioned below should be satisfied for returning to the normal status.

- The voltage of each of the batteries is in the range from the overcharge detection voltage n (V_{CUn}) to overdischarge detection voltage n (V_{DLn}).
- The VINI pin voltage is in the range of the charge overcurrent detection voltage (V_{CIOV}) to discharge overcurrent 1 detection voltage (V_{DIOV1}).
- The PSI pin voltage is higher than the PSI pin reverse voltage "H" (VPSIH).

Caution After a battery is connected, there may be cases when discharging cannot be performed. In this case, this IC returns to the normal status when any of the following conditions is satisfied.

- (1) Connecting a charger
- (2) Shorting between the VM pin and the VSS pin
- (3) Changing the PSI pin voltage to be $V_{DS} \rightarrow 0 \ V \rightarrow V_{DS}$

2. Overcharge status

When the voltage of any of the batteries exceeds the overcharge detection voltage n (V_{CUn}) and the status continues for the overcharge detection delay time (t_{CU})*1 or longer, the CO pin changes to VM pin voltage. This is the overcharge status. In this case, the charge control FET is turned off and charging is stopped.

The overcharge status is released if either condition mentioned below is satisfied.

- (1) $V_{VM} < 0.3 \ V$ typ., and voltage of all batteries $\leq V_{CLn}$
- (2) $V_{VM} \ge 0.3 \text{ V typ.}$, and voltage of all batteries $\le V_{CUn}$

*1. Refer to "6. Delay time setting" for details.

Remark V_{VM}: VM pin voltage

 V_{CUn} : Overcharge detection voltage n (n = 1, 2, 3, 4, 5) V_{CLn} : Overcharge release voltage n (n = 1, 2, 3, 4, 5)

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3. Overdischarge status

When the voltage of any of the batteries decreases to the overdischarge detection voltage n (V_{DLn}) or lower and the status continues for the overdischarge detection delay time (t_{DL})*1 or longer, the DO pin changes to the V_{SS} level. This is the overdischarge status. The discharge control FET is turned off and discharging is stopped.

The overdischarge status is released if either condition mentioned below is satisfied.

- (1) $V_{VM} \le 0 \text{ V typ.}$, and voltage of all batteries $\ge V_{DLn}$
- (2) $V_{VM} > 0$ V typ., and voltage of all battery $\geq V_{DUn}$

*1. Refer to "6. Delay time setting" for details.

Remark V_{VM}: VM pin voltage

V_{DLn}: Overdischarge detection voltage n (n = 1, 2, 3, 4, 5) V_{DUn}: Overdischarge release voltage n (n = 1, 2, 3, 4, 5)

3. 1 With power-down function

When this IC reaches the overdischarge status, the VM pin is pulled up to the V_{DD} level by a resistance between VM pin and VDD pin (R_{VMD}). If the VM pin voltage changes to 0.7 V typ. or higher, the power-down function starts to operate and most operations in this IC halt. The CO pin changes to VM pin voltage. In this case, the charge control FET is turned off and charging is stopped.

By connecting a battery charger, the power-down function is released when the VM pin voltage is 0.7 V typ. or lower.

4. Discharge overcurrent status

When the discharge current increases to a certain value or more, the VINI pin voltage increases to the level of discharge overcurrent 1 detection voltage (VDIOV1) or higher. If the condition continues for the discharge overcurrent 1 detection delay time (tDIOV1)*1 or longer, the DO pin changes to the Vss level. This is the discharge overcurrent status. The discharge control FET is turned off and discharging is stopped.

Discharge overcurrent is detected at the following three levels: VDIOV1, VDIOV2, and VSHORT. When discharge overcurrent 2 detection voltage (VDIOV2) and load short-circuiting detection voltage (VSHORT) are detected, the same operations as VDIOV1 detection are performed.

4. 1 Release condition of discharge overcurrent status "Load disconnection"

Under the discharge overcurrent status, VM pin and VSS pin are shorted by R_{VMS} in this IC. However, the VM pin voltage is the V_{DD} level due to the load as long as the load is connected. When the load is disconnected, the VM pin voltage returns to the Vss level. When the VM pin voltage returns to $V_{DS}/3$ or lower, this IC releases the discharge overcurrent status.

R_{VMD} is not connected in the discharge overcurrent status.

4. 2 Release condition of discharge overcurrent status "Charger connection"

Under the discharge overcurrent status, VDD pin and VM pin are shorted by R_{VMD} in this IC. When a battery is connected to a charger and VM pin voltage returns to V_{DIOV1} or lower, this IC releases the discharge overcurrent status.

R_{VMS} is not connected in the discharge overcurrent status.

5. Charge overcurrent status

When the charge current increases to a certain value or more, the VINI pin voltage decreases to the level of charge overcurrent detection voltage (Vciov) or lower. If the status continues for the charge overcurrent detection delay time (tciov)*1 or longer, the CO pin voltage changes to the VM pin voltage. This is the charge overcurrent status. In this case, the charge control FET is turned off and charging is stopped. The VM pin is pulled up to the VDD level by a resistance between VM pin and VDD pin (RVMD).

The charge overcurrent status is released if the VM pin voltage increases 0.3 V typ. or higher.

*1. Refer to "6. Delay time setting" for details.

6. Delay time setting

Users are able to set delay time for the period from when this IC detects change in the voltage of any of the batteries or the VINI pin until when it outputs to the CO pin or DO pin. The discharge overcurrent 1 detection delay time (t_{DIOV1}) is determined by constant current in this IC and an external capacitor. The other detection delay times are fixed internally.

6. 1 Other than discharge overcurrent 1 detection delay time (tDIOV1)

The detection delay times are determined by dividing a clock of approximately 4 kHz by the counter.

Remark t_{DIOV2} and t_{SHORT} start when V_{DIOV2} is detected. When V_{SHORT} is detected over t_{SHORT} after the detection of V_{DIOV2}, this IC turns the discharge control FET off within t_{DIOV2} or t_{SHORT} of each detection.

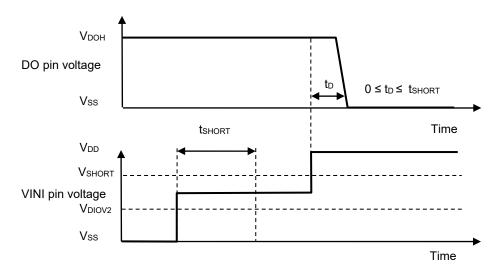


Figure 5

6. 2 Discharge overcurrent 1 detection delay time (tDIOV1)

In the discharge overcurrent 1 detection, when the VINI pin voltage increases to discharge overcurrent 1 detection voltage (VDIOV1) or higher, the internal circuit of this IC starts charging to an external capacitor connected to the CIT pin via the CIT pin current (ICIT) = 120 nA typ. When the CIT pin voltage increases to the CIT pin detection voltage (VCIT) or higher, the DO pin voltage changes to Vss level. This period is discharge overcurrent 1 detection delay time (IDIOV1).

t_{DIOV1} is calculated by the following formula.

 $t_{\text{DIOV1}}\left[s\right] = C_{\text{CIT}}\left[F\right] \times V_{\text{CIT}}\left[V\right] / I_{\text{CIT}}\left[A\right]$

If C_{CIT} = 0.01 μF , t_{DIOV1} is calculated as follows:

 t_{DIOV1} [s] = 0.01 $\mu\text{F}\times1.2$ V typ. / 120 nA typ. = 100 ms typ.

7. 0 V Battery charge function

Regarding how to charge a self-discharged battery (0 V battery), users are able to select either function mentioned below.

- (1) 0 V battery charge enabled
 - A 0 V battery is charged when charger voltage is higher than the 0 V battery charge starting charger voltage (V_{0CHA}).
- (2) 0 V battery charge inhibited
 - A 0 V battery is not charged when the voltage of any of the batteries is the 0 V battery charge inhibition battery voltage n (V_{OINHn}) or lower.

Caution When the VDD pin voltage is lower than the minimum value of operation voltage between the VDD pin and VSS pin (VDSOP), this IC's operation is not assured.

Remark n = 1, 2, 3, 4, 5

8. PSI pin

When the PSI pin is activated, the power-saving function starts to operate, and most operations halt. In this case, the CO pin changes to the VM pin level, and DO pin changes to the Vss level.

 PSI pin
 CO pin
 DO pin

 $V_{PSIH} \le PSI$ pin voltage ≤ V_{DD} level
 "H"
 "H"

 $V_{PSIL} < PSI$ pin voltage < V_{PSIH} Maintains the status
 Maintains the status

 V_{SS} level ≤ PSI pin voltage ≤ V_{PSIL} VM pin level
 Vss level

Table 10 Status Set by PSI Pin

This IC is initialized and becomes the normal status by deactivating the PSI pin after activating PSI pin and enabling the power-saving function. As a result, each detection operation is carried out after returning to the normal status.

■ Timing Charts

1. Overcharge detection, overdischarge detection

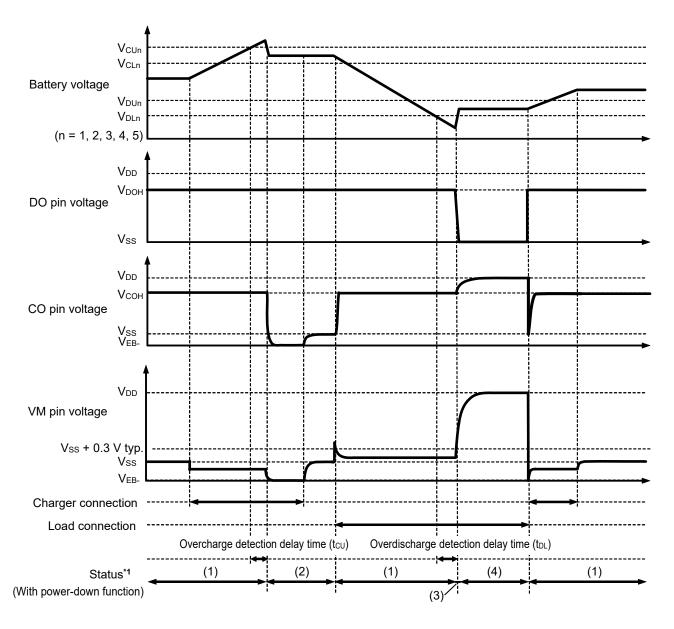


Figure 6

*1. (1): Normal status

(2): Overcharge status

(3): Overdischarge status

(4): Power-down status

2. Discharge overcurrent detection

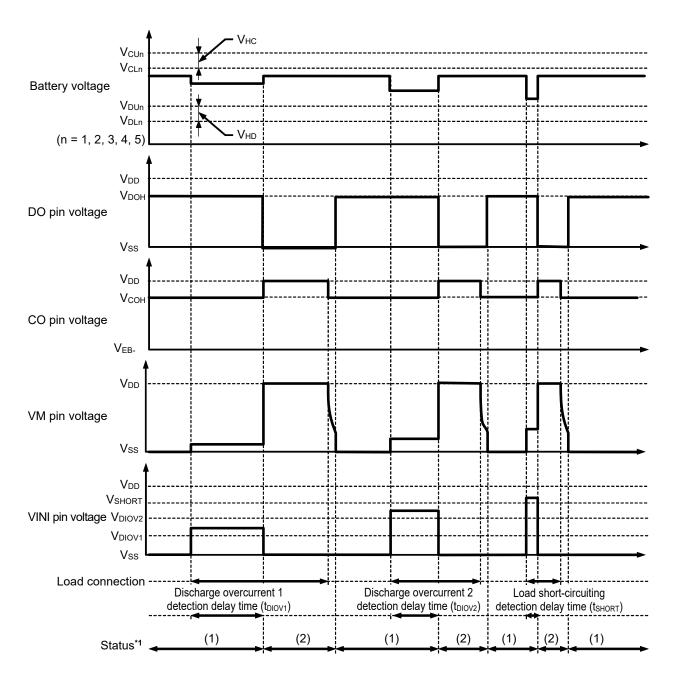


Figure 7

*1. (1): Normal status

(2): Discharge overcurrent status

3. Charge overcurrent detection

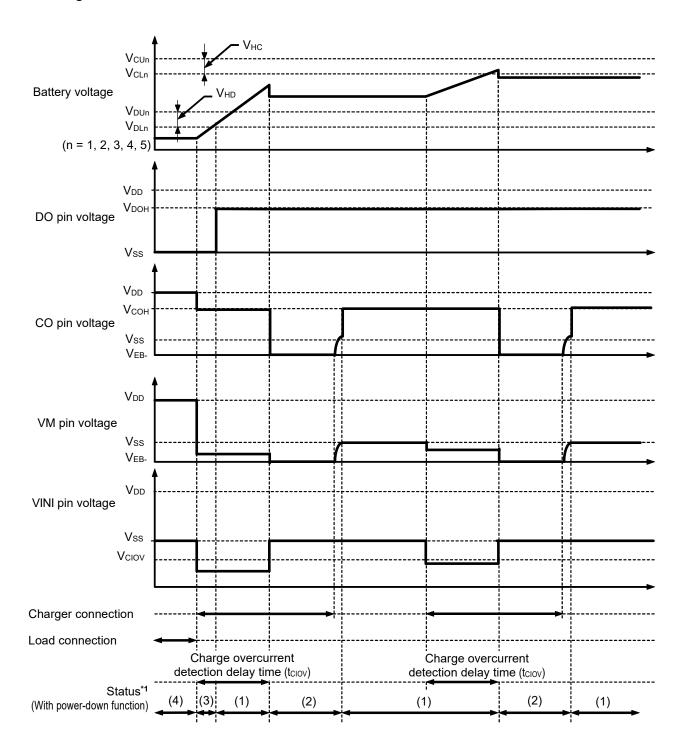


Figure 8

*1. (1): Normal status

(2) : Charge overcurrent status(3) : Overdischarge status

(4): Power-down status

■ Connection Examples of Battery Protection IC

1. S-82B4A Series (4-serial cell)

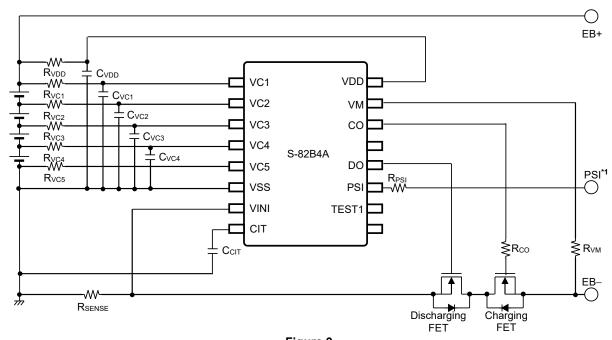


Figure 9

*1. If you do not use the power-saving function, connect the PSI pin to the VDD pin.

Remark Regarding the recommended values for external components, refer to "Table 11 Constants for External Components".

2. S-82B5A Series (5-serial cell)

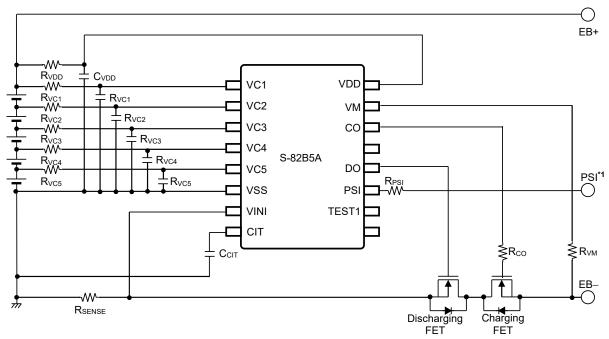


Figure 10

*1. If you do not use the power-saving function, connect the PSI pin to the VDD pin.

Remark Regarding the recommended values for external components, refer to "Table 11 Constants for External Components".

Unit Symbol Тур. 100 R_{VDD} Ω R_{VCn} (n = 1, 2, 3, 4, 5) 1 $\mathsf{k}\Omega$ 1 $k\Omega$ **R**_{PSI} R_{CO} 1 $\mathsf{k}\Omega$ 1 $k\Omega$ R_{VM} **R**SENSE $\text{m}\Omega$ 1 μF C_{VDD}

Table 11 Constants for External Components

Caution 1. The constants may be changed without notice.

Ccit

 C_{VCn} (n = 1, 2, 3, 4, 5)

Sufficient evaluation of transient power supply fluctuation and overcurrent protection function with the actual application is needed to determine the proper constants when setting the filter constants between the VDD pin and VSS pin. Contact our sales representatives if setting the constants between the VDD pin and VSS pin to anything other than the recommended values.

0.1

0.01 or more

μF

μF

3. It has not been confirmed whether the operation is normal or not in circuits other than the connection examples. In addition, the connection examples and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.

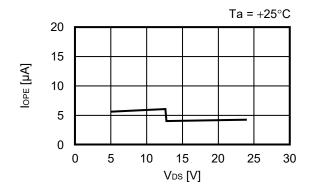
Precautions

- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Batteries can be connected in any order; however, there may be cases when discharging cannot be performed after a battery is connected. In this case, this IC returns to the normal status when any of the following conditions is satisfied.
 - (1) Connecting a charger
 - (2) Shorting between the VM pin and the VSS pin
 - (3) Changing the PSI pin voltage to be $V_{DS} \, o \, 0 \; V \, o \, V_{DS}$
- If an overcharged battery and an overdischarged battery intermix, this IC will change to the overcharge and overdischarge statuses. Therefore, in this case, both charging and discharging are impossible.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

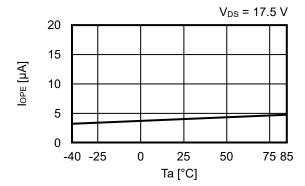
■ Characteristics (Typical Data)

1. Current consumption

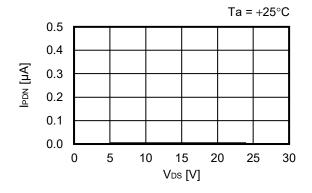
1. 1 IOPE VS. VDS



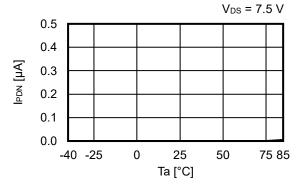
1. 2 IOPE vs. Ta



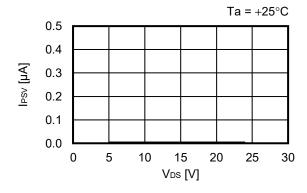
1. 3 IPDN VS. VDS



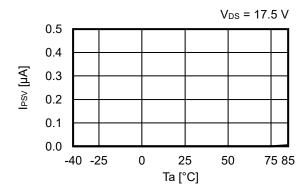
1. 4 IPDN vs. Ta



1. 5 IPSV VS. VDS

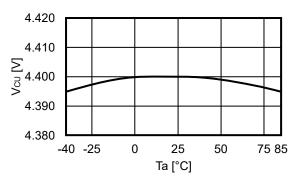


1. 6 I_{PSV} vs. Ta

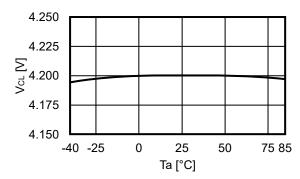


2. Detection voltage, release voltage

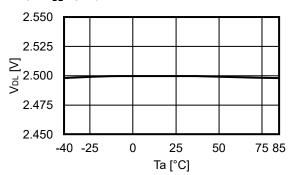
2. 1 Vcu vs. Ta



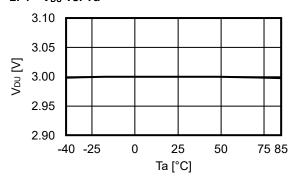
2. 2 V_{CL} vs. Ta



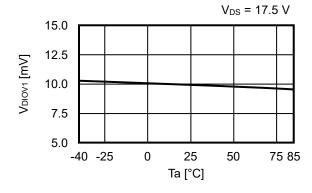
2. 3 V_{DL} vs. Ta



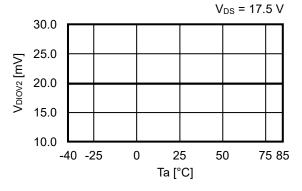
2. 4 V_{DU} vs. Ta



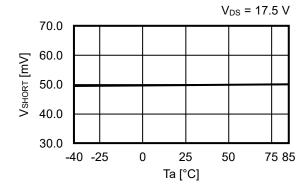
2. 5 V_{DIOV1} vs. Ta



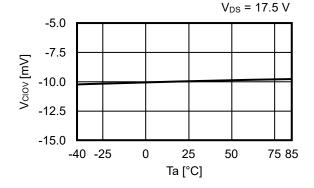
2. 6 V_{DIOV2} vs. Ta



2. 7 V_{SHORT} vs. Ta

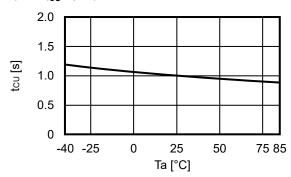


2. 8 V_{CIOV} vs. Ta

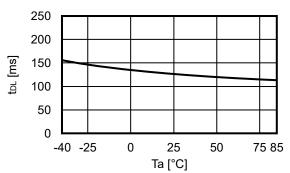


3. Delay time function

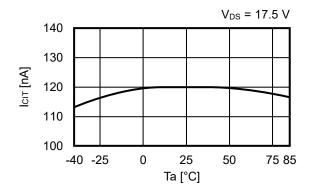
3. 1 t_{CU} vs. Ta



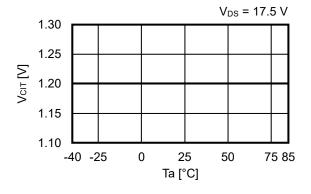
3. 2 t_{DL} vs. Ta



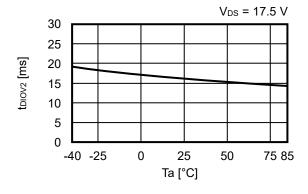
3. 3 Icit vs. Ta



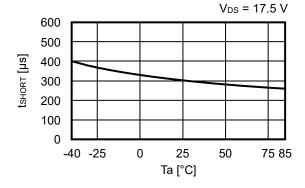
3. 4 V_{CIT} vs. Ta



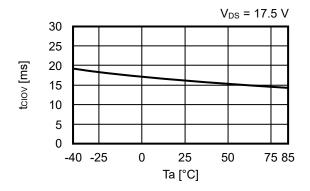
3. 5 t_{DIOV2} vs. Ta



3. 6 tshort vs. Ta

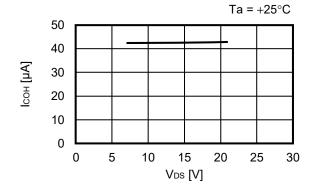


3. 7 tciov vs. Ta

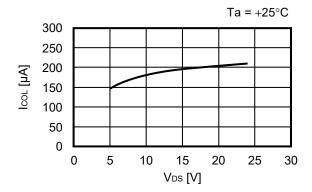


4. Output pin

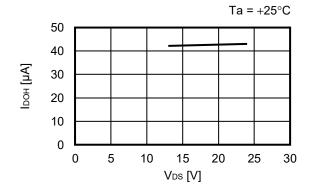
4. 1 Icon vs. VDS



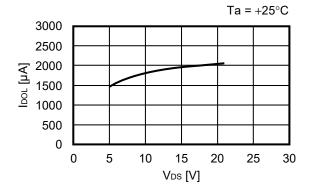
4. 2 Icol vs. VDS



4. 3 IDOH VS. VDS

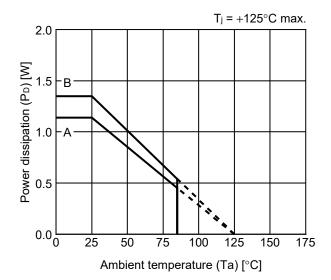


4. 4 IDOL VS. VDS



■ Power Dissipation

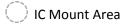
16-Pin TSSOP

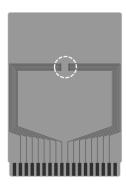


Board	Power Dissipation (P _D)				
Α	1.14 W				
В	1.35 W				
С	_				
D	-				
E	-				

16-Pin TSSOP Test Board

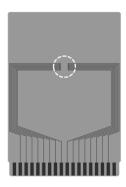
(1) Board A





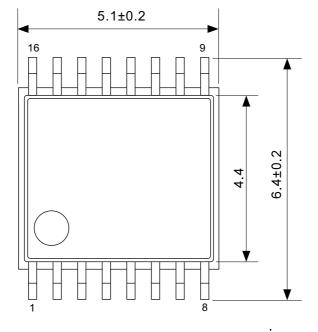
Item		Specification	
Size [mm]		114.3 x 76.2 x t1.6	
Material		FR-4	
Number of copper foil layer		2	
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070	
	2	-	
	3	-	
	4	74.2 x 74.2 x t0.070	
Thermal via		-	

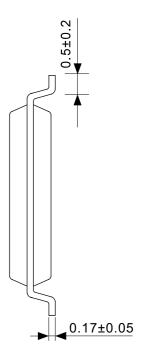
(2) Board B

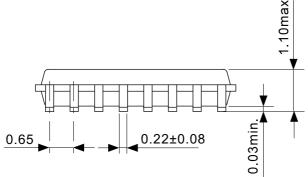


Item		Specification	
Size [mm]		114.3 x 76.2 x t1.6	
Material		FR-4	
Number of copper foil layer		4	
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070	
	2	74.2 x 74.2 x t0.035	
	3	74.2 x 74.2 x t0.035	
	4	74.2 x 74.2 x t0.070	
Thermal via		-	

No. TSSOP16-A-Board-SD-1.0

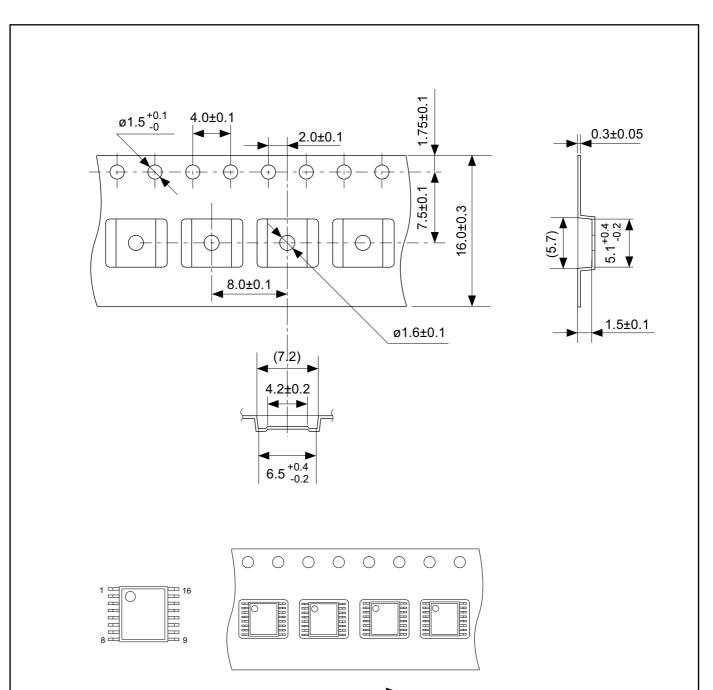






No. FT016-A-P-SD-1.2

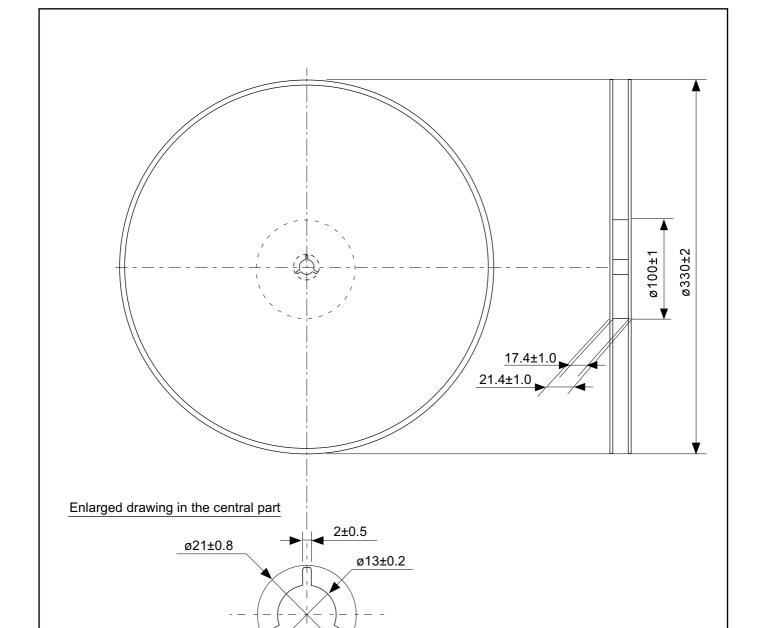
TITLE	TSSOP16-A-PKG Dimensions			
No.	FT016-A-P-SD-1.2			
ANGLE	$\Phi \ominus$			
UNIT	mm			
ABLIC Inc.				



Feed direction

No. FT016-A-C-SD-1.1

TITLE	TSSOP16-A-Carrier Tape			
No.	FT016-A-C-SD-1.1			
ANGLE				
UNIT	mm			
ABLIC Inc.				



No. FT016-A-R-S1-2.0

TITLE	TSSOP16-A- Reel						
No.	FT016-A-R-S1-2.0						
ANGLE		QTY.	4,000				
UNIT	mm						
ABLIC Inc.							

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